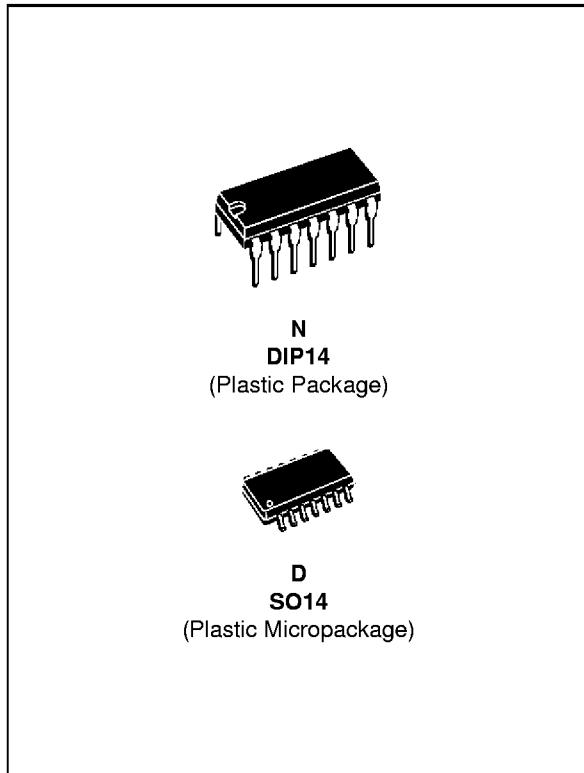


HIGH PERFORMANCE
 QUAD BIPOLAR OPERATIONAL AMPLIFIER

- HIGH GAIN BANDWIDTH PRODUCT : **25MHz**
- HIGH SLEW RATE : **15V/ μ s**
- SINGLE OR DUAL SUPPLY OPERATION : **3V TO 30V** ($\pm 1.5V$ to $\pm 15V$)
- LOW VOLTAGE NOISE : **14nV/ $\sqrt{\text{Hz}}$**
- NO PHASE INVERSION
- ESD TOLERANCE : 2kV
- LATCH-UP IMMUNITY
- **SPICE MACROMODEL INCLUDED IN THIS SPECIFICATION**

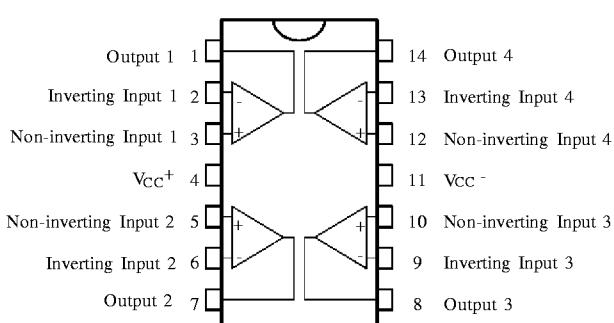

DESCRIPTION

The TSH24 is a quad bipolar operational amplifier offering a single supply operation from 3V to 30V with very good performances : medium speed (25MHz), unity gain stability and low noise.

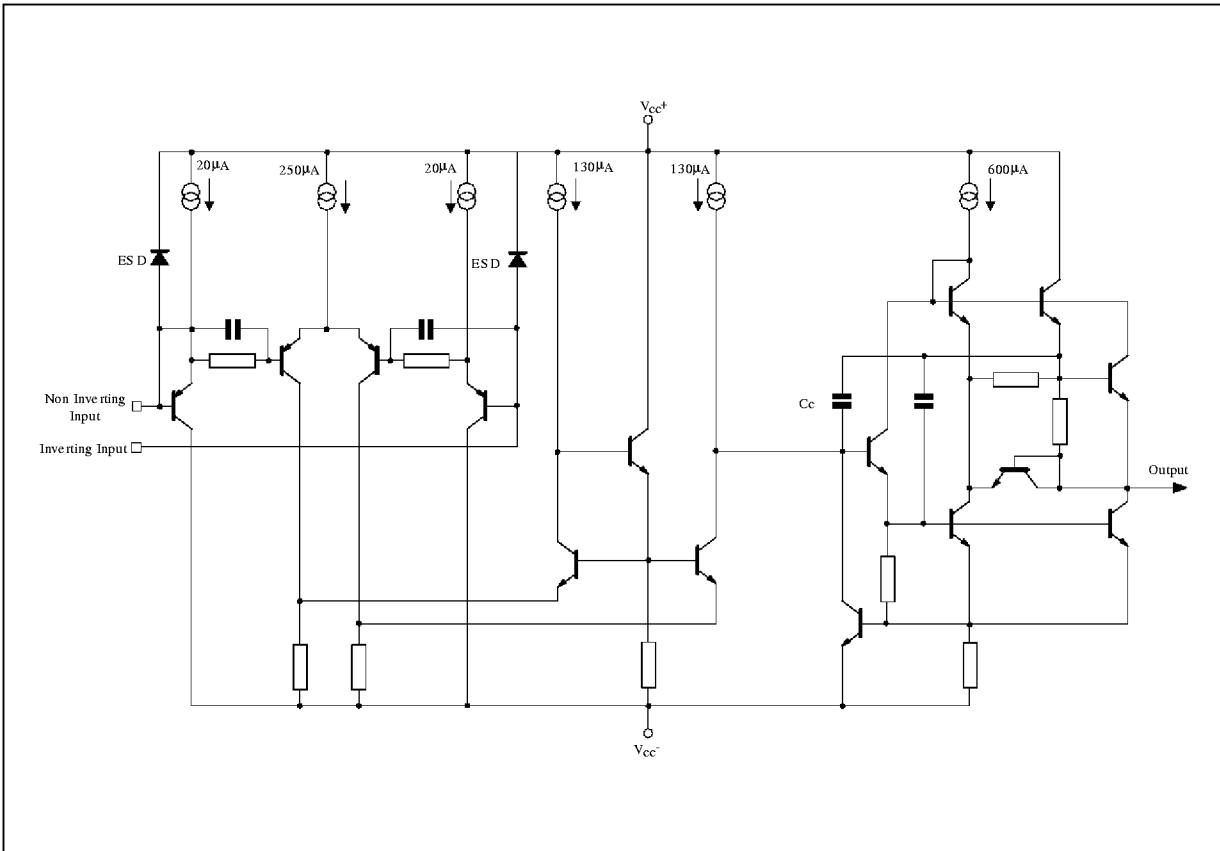
The TSH24 is therefore an enhanced replacement of standard quad operational amplifiers.

ORDER CODES

Part Number	Temperature Range	Package	
		N	D
TSH24I	-40, +125°C	•	•

PIN CONNECTIONS (top view)


SCHEMATIC DIAGRAM (1/4 TSH24)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	± 18 or $+36$	V
V_{id}	Differential Input Voltage - (note 1)	± 36	V
V_i	Input Voltage - (note 1)	± 18	V
	Output Short-Circuit Duration - (note 2)	Infinite	
T_{oper}	Operating Free-air Temperature Range	-40 to +125	°C
T_j	Maximum Junction Temperature	+150	°C
T_{stg}	Storage Temperature	-65 to +150	°C
P_{tot}	Maximum Power Dissipation - (note 2)	500	mW

Notes : 1. Either or both input voltages must not exceed the magnitude of V_{CC}^+ or V_{CC}^-
2. Power dissipation must be considered to ensure maximum junction temperature (T_j) is not exceeded

OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	3 to 30	V

ELECTRICAL CHARACTERISTICS $V_{CC^+} = +15V, V_{CC^-} = -15V, T_{amb} = 25^\circ C$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{io}	Input Offset Voltage ($V_{ic} = 0V, V_o = 0V$) $V_{CC^+} = +15V, V_{CC^-} = -15V$ $T_{min} \leq T \leq T_{max}$. $V_{CC^+} = +5V, V_{CC^-} = 0V$			2.5 3.5 2.5	mV
ΔV_{io}	Input Offset Voltage Drift ($V_{ic} = 0V, V_o = 0V, T = -40, +85^\circ C$)		2		$\mu V/\text{ }^\circ C$
I_{io}	Input Offset Current ($V_{ic} = 0V, V_O = 0V$)		3	65	nA
I_{ib}	Input Bias Current ($V_{ic} = 0V, V_O = 0V$)		100	650	nA
V_{icm}	Common Mode Input Voltage Range		V_{CC^-} to $V_{CC^+} - 1.8V$		V
A_{vd}	Large Signal Voltage Gain ($R_L = 2k\Omega, V_O = 0V$ to $+10V$) $T_{min} \leq T \leq T_{max}$.	32 20	100		V/mV
$\pm V_{opp}$	Output Voltage Swing ($V_{id} = \pm 1V$) $V_{CC^+} = +15V, V_{CC^-} = -15V$ $R_L = 2k\Omega$ $R_L = 10k\Omega$ $V_{CC^+} = +5V, V_{CC^-} = 0V$ $R_L = 2k\Omega$	13.4 13.4 3.7	13.9 -13.9 14 -14.7 V_{OH} V_{OL}	-13.5 -14.1	V
I_o	Output Short Circuit Current ($V_{id} = \pm 1V, V_o = 0V$) Source Sink	25 25	37 37		mA
CMR	Common Mode Rejection Ratio ($V_{ic} = -15V$ to $+13.2V$)	80	100		dB
SVR	Supply Voltage Rejection Ratio $V_{CC^+} / V_{CC^-} = +15V / -15V$ to $+5V / -5V$	90	105		dB
I_{cc}	Supply Current ($V_O = 0V$, no load, each amplifier) $V_{CC^+} = +15V, V_{CC^-} = -15V$ $T_{min} \leq T \leq T_{max}$. $V_{CC^+} = +5V, V_{CC^-} = 0V$		2.15 3 2.75	2.75 3 2.75	mA
SR	Slew Rate ($V_i = -10V$ to $+10V, C_L = 100pF, R_L = 2k\Omega, A_V = +1$)	8	15		V/ μs
GBP	Gain Bandwidth Product ($f = 100kHz, R_L = 2k\Omega, C_L = 100pF$)	17	25		MHz
B	Unity Gain Bandwidth (Open loop)		5		MHz
$\emptyset m$	Phase Margin $R_L = 2k\Omega$ $R_L = 2k\Omega, C_L = 100pF$		50 40		Degrees
e_n	Equivalent Input Noise Voltage ($R_S = 100\Omega, f = 1kHz$)		14		nV/\sqrt{Hz}
V_{O1}/V_{O2}	Channel Separation ($f = 20Hz$ to $20kHz$)		120		dB
THD	Total Harmonic Distortion ($V_{CC} = \pm 15V, f = 1kHz, A_{VCL} = 20dB, R_L = 600\Omega, V_o = 3Vrms$)		0.003		%

MACROMODEL

** Standard Linear Ics Macromodels, 1993.

CONNECTIONS :

- * 1 INVERTING INPUT
- * 2 NON-INVERTING INPUT
- * 3 OUTPUT
- * 4 POSITIVE POWER SUPPLY
- * 5 NEGATIVE POWER SUPPLY
- .SUBCKT TSH24 1 3 24 5 (analog)

```
.MODEL MDTH D IS=1E-8 KF=7.976636E-15
CJO=10F
* INPUT STAGE
CIP 2 5 1.200000E-11
CIN 1 5 1.200000E-11
EIP 10 5 2 5 1
EIN 16 5 1 5 1
RIP 10 11 1.083333E+00
RIN 15 16 1.083333E+00
RIS 11 15 8.942641E+00
DIP 11 12 MDTH 400E-12
DIN 15 14 MDTH 400E-12
VOFP 12 13 DC 0
VOFN 13 14 DC 0
IPOL 13 5 2.400000E-04
CPS 11 15 10.5E-09
DINN 17 13 MDTH 400E-12
VIN 17 5 -0.200000e+00
DINR 15 18 MDTH 400E-12
VIP 4 18 1.800000E+00
FCP 4 5 VOFP 7.750000E+00
FCN 5 4 VOFN 7.750000E+00
FIBP 2 5 VOFN 5.000000E-04
FIBN 5 1 VOFP 5.000000E-04
```

- * AMPLIFYING STAGE
- FIP 5 19 VOFP 6.708333E+02
- FIN 5 19 VOFN 6.708333E+02
- GVNEG 5 19 5 13 1.395908E-05
- GVPOS 5 19 4 13 1.395908E-05
- RG1 19 5 8.056996E+04
- RG2 19 4 8.056996E+04
- CC 19 29 1.100000E-08
- HZTP 30 29 VOFP 6.545046E+01
- HZTN 5 30 VOFN 6.545046E+01
- DOPM 19 22 MDTH 400E-12
- DONM 21 19 MDTH 400E-12
- HOPM 22 28 VOUT 4.054054E+03
- VIPM 28 4 1.500000E+02
- HONM 21 27 VOUT 4.054054E+03
- VINM 5 27 1.500000E+02
- RPM1 5 80 1E+06
- RPM2 4 80 1E+06
- GAVPH 5 82 19 80 6.00E-07
- RAVPHGH 82 4 3333222
- RAVPHGB 82 5 3333222
- RAVPHDH 82 83 1000000
- RAVPHDB 82 84 1000000
- CAVPHH 4 83 0.12243E-12
- CAVPHB 5 84 0.12243E-12
- EOUT 26 23 82 5 1
- VOUT 23 5 0
- ROUT 26 3 2.472597E+01
- COUT 3 5 1.000000E-12
- DOP 19 25 MDTH 400E-12
- VOP 4 25 1.824860E+00
- DON 24 19 MDTH 400E-12
- VON 24 5 1.824860E+00

.ENDS

ELECTRICAL CHARACTERISTICS

$V_{CC} = \pm 15V$, $T_{amb} = 25^\circ C$ (unless otherwise specified)

Symbol	Conditions	Value	Unit
V_{id}		0	mV
A_{vd}	$R_L = 2k\Omega$	100	dB
I_{CC}	No load, per operator	2	mA
V_{icm}		-15.2 to 13.8	V
V_{OH}	$R_L = 2k\Omega$	+13.9	V
V_{OL}	$R_L = 2k\Omega$	-13.9	V
I_{sink}	$V_O = 0V$	40	mA
I_{source}	$V_O = 0V$	40	mA
GBP	$R_L = 2k\Omega$, $C_L = 100pF$	34	MHz
SR	$R_L = 2k\Omega$, $C_L = 100pF$	10	V/ μ s
\emptyset_m	$R_L = 2k\Omega$, $C_L = 100pF$	36	Degrees
\emptyset_m	$R_L = 2k\Omega$, $C_L = 300pF$	26	Degrees

APPLICATIONS INFORMATION

TSH24 IN COMPARATOR APPLICATION

The TSH24 is a quad high performances operational amplifier featuring speed of 30MHz and single supply operation from 3V to 30V.

Most of operational amplifiers are not suited for comparator use because of low transition speed, output signal incompatible with standard logics level and mainly, phase inversion.

The phase inversion occurs when a strong differential signal is applied to the device inputs. The output level is then inverted and shows a wrong logic state.

TSH24 does not present this problematic behaviour.

Figure 1 : Basic comparator application

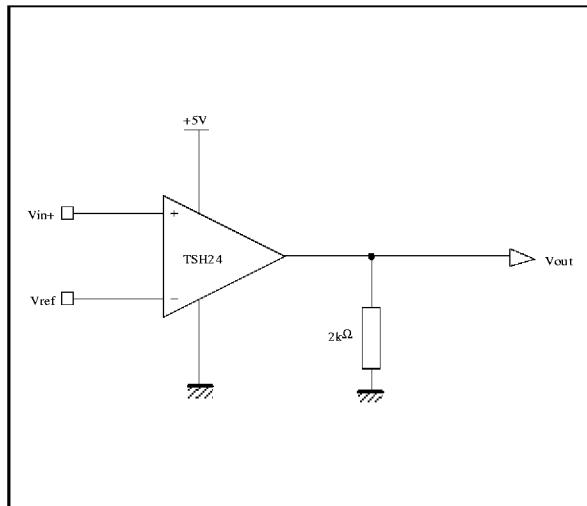
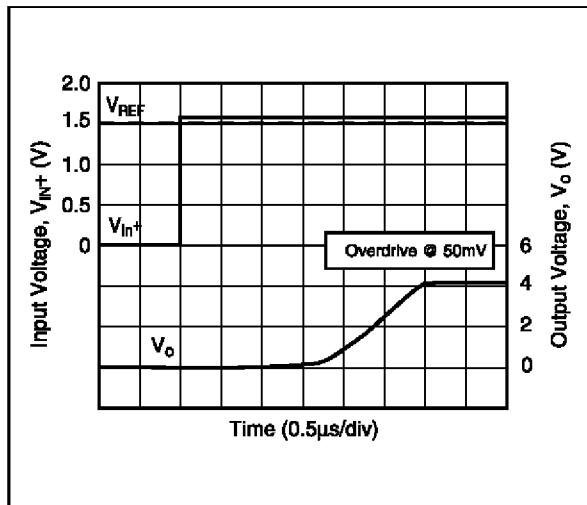


Figure 3 : Transition speed @ 50mV overdrive



Displayed curves below show the device response in standard comparator configuration without external components.

Transition speed : Typical transition speed under a single 5V supply voltage is about $2\mu s$ from 50mV overdrive. V_{OH} min. is 3.7V and V_{OL} max. is 0.2V ($2k\Omega$ load) making it compatible with standard logic families.

Figures 3 & 4 show output signal transition for a 50mV and 250mV input signal overdrive respectively of $3\mu s$ and $1\mu s$.

Figure 2 : Operating conditions

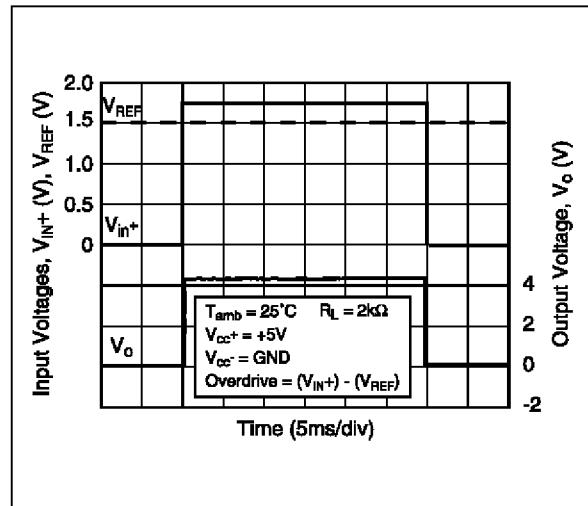
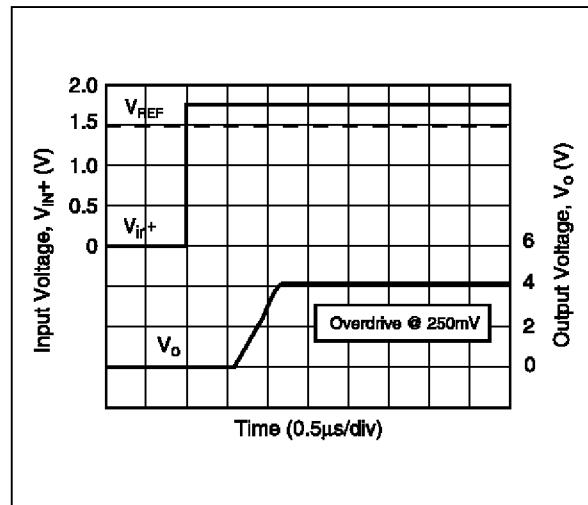


Figure 4 : Transition speed @ 250mV overdrive



PHASE INVERSION

At high differential input voltage, the TSH24 keeps the right output level thanks to its specific input structures.

The advantage is obvious on the following figures and can be also an advantage in linear use when saturation might occur.

Figure 5 : Behaviour with TSH24

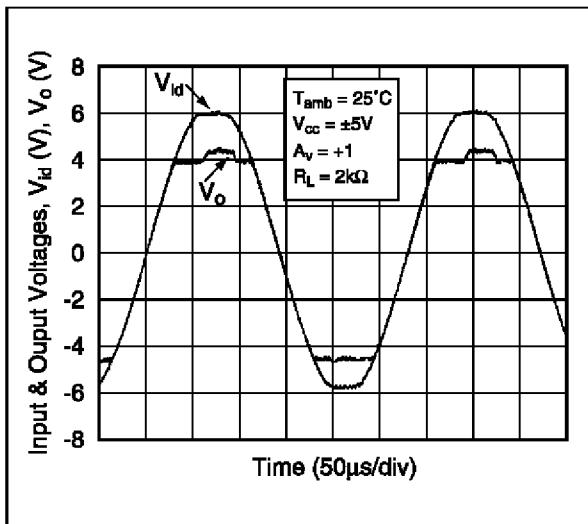
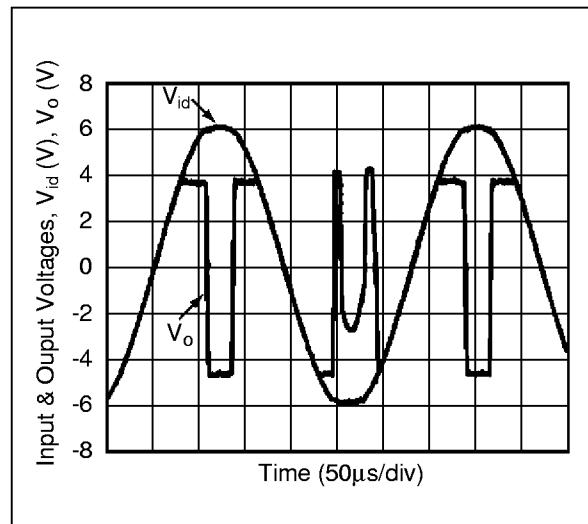
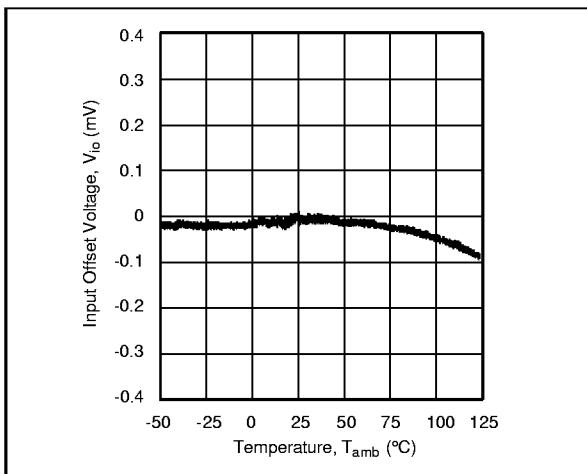
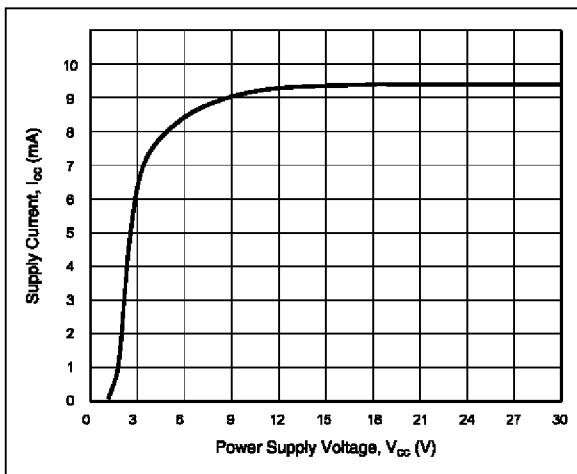
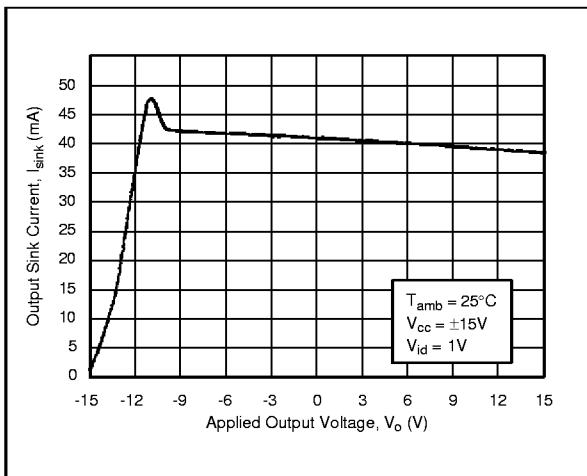
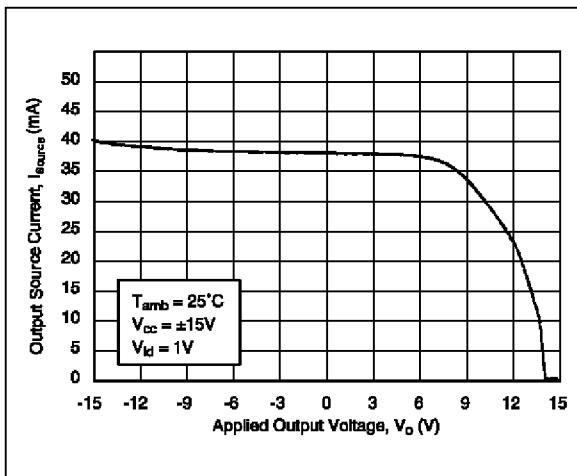
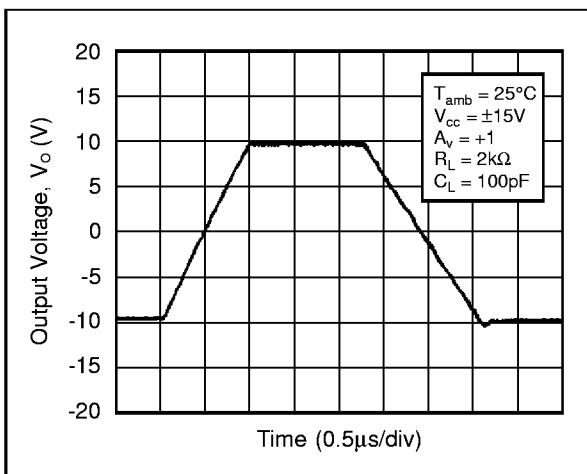
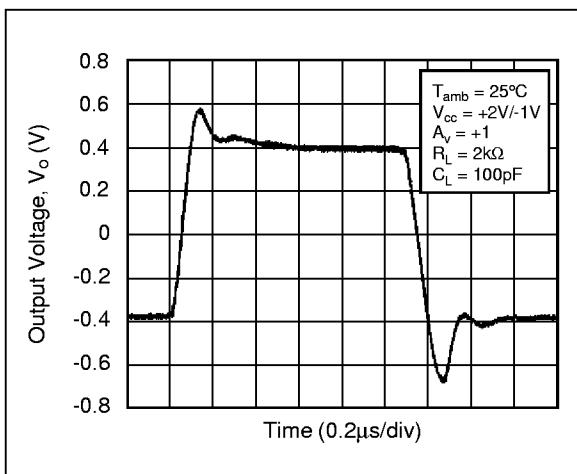


Figure 5 & 6 show the behaviour in follower stage with saturation output of TSH24 versus 15MHz standard operational amplifier.

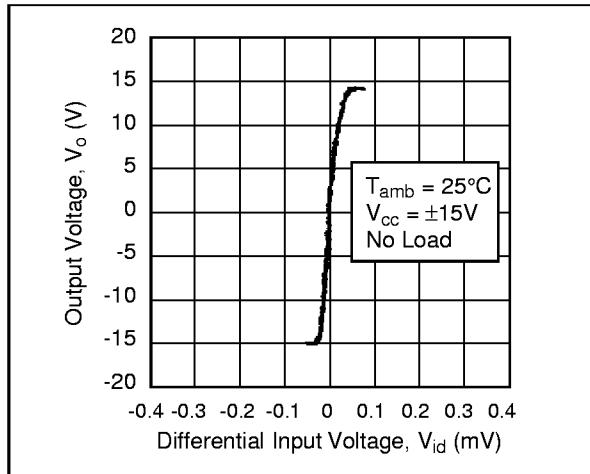
Figure 6 : Saturation behaviour with 15MHz standard operational amplifier



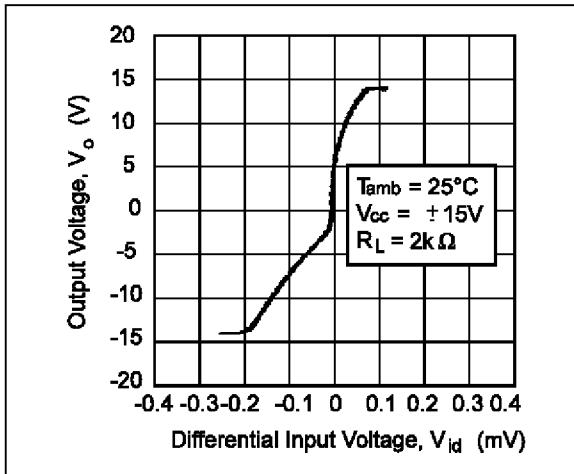
INPUT OFFSET VOLTAGE DRIFT VERSUS TEMPERATURE

SUPPLY CURRENT VERSUS SUPPLY VOLTAGE (ALL OP-AMP)

SINK CURRENT

SOURCE CURRENT

SLEW RATE @ 30V

SLEW RATE @ 3V


TSH24

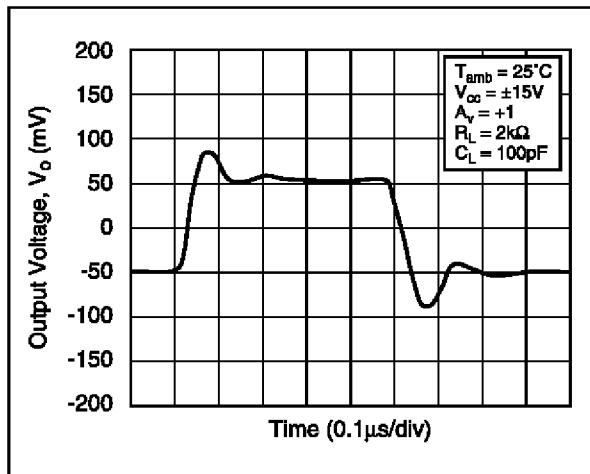
LARGE SIGNAL VOLTAGE GAIN @ NO LOAD



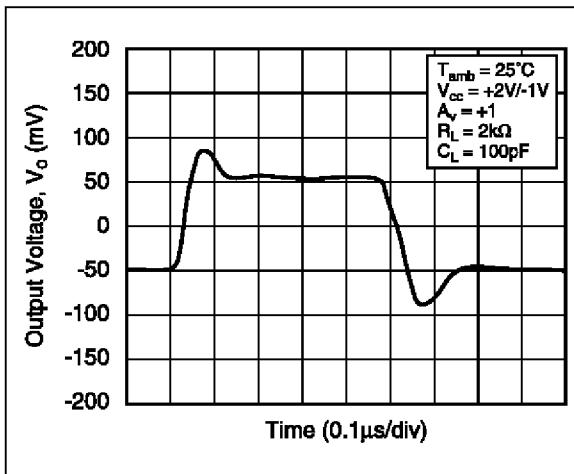
LARGE SIGNAL VOLTAGE GAIN @ LOAD



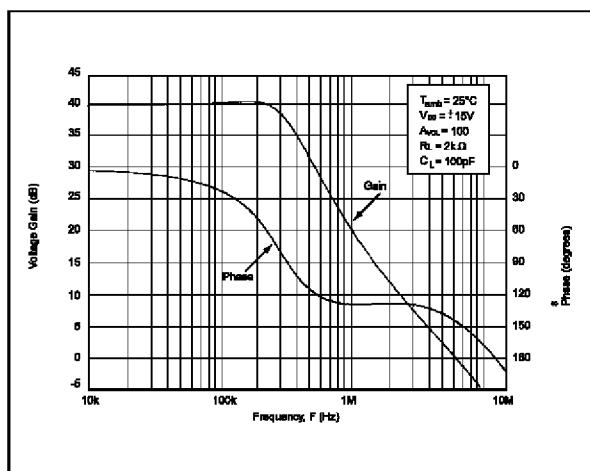
SMALL SIGNAL RESPONSE @ 30V



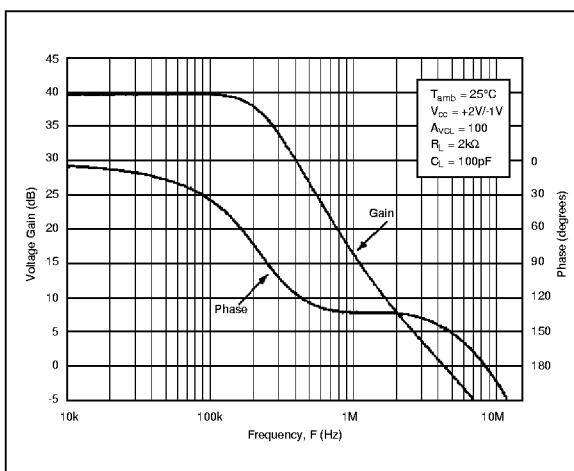
SMALL SIGNAL RESPONSE @ 3V



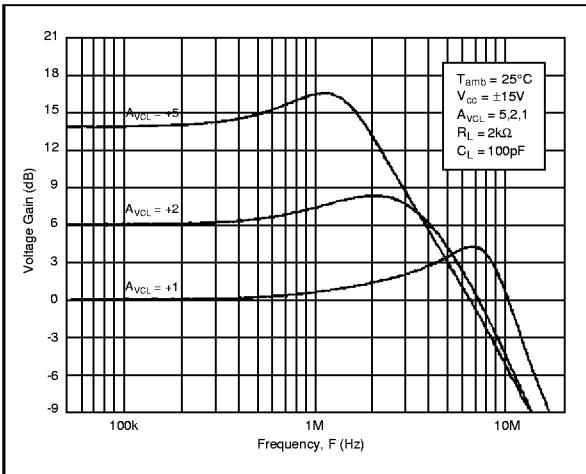
UNITY GAIN BANDWIDTH @ 30V



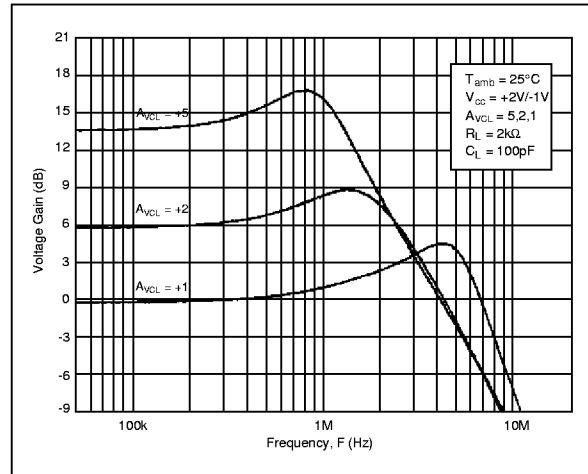
UNITY GAIN BANDWIDTH @ 3V



CLOSED LOOP BANDWIDTH @ 30V

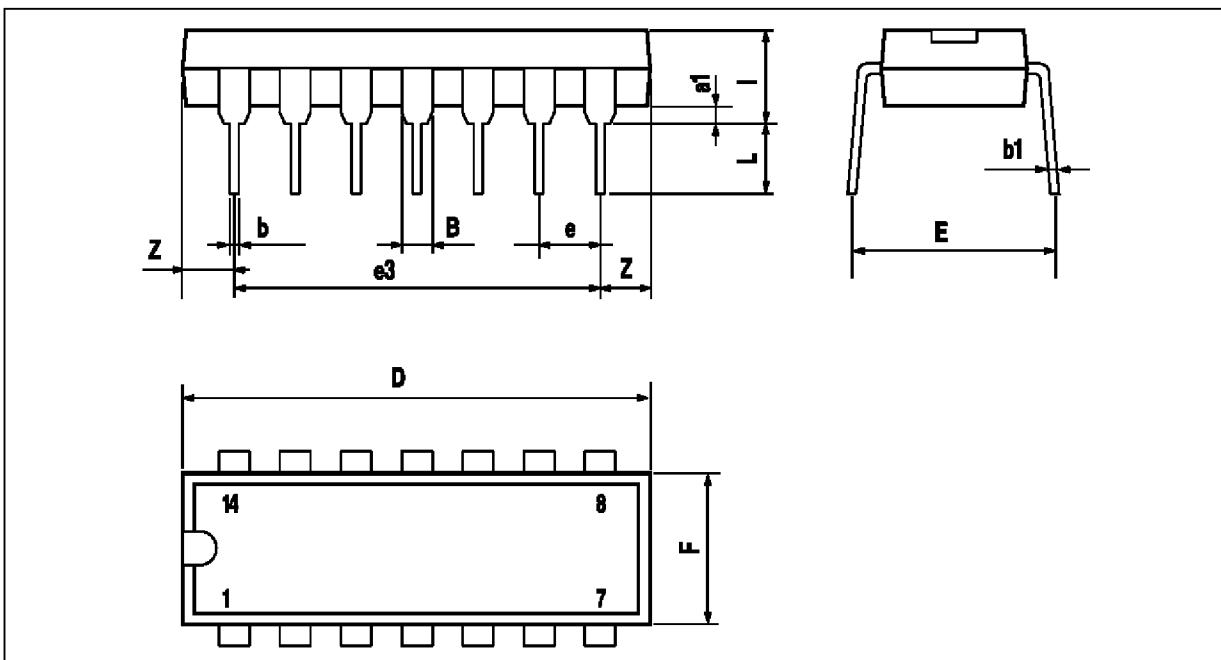


CLOSED LOOP BANDWIDTH @ 3V



PACKAGE MECHANICAL DATA

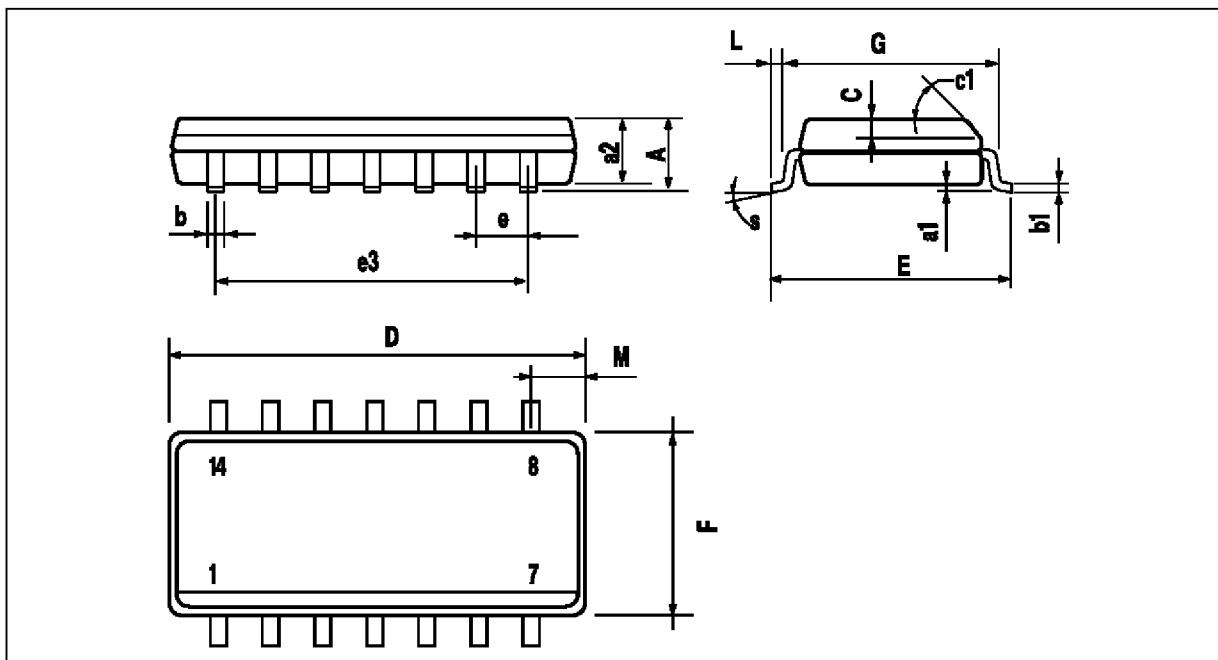
14 PINS - PLASTIC DIP



Dim.	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
a1	0.51			0.020		
B	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
i			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100

PACKAGE MECHANICAL DATA

14 PINS - PLASTIC MICROPACKAGE (SO)



Dim.	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a ₁	0.1		0.2	0.004		0.008
a ₂			1.6			0.063
b	0.35		0.46	0.014		0.018
b ₁	0.19		0.25	0.007		0.010
C		0.5			0.020	
c ₁	45° (typ.)					
D	8.55		8.75	0.336		0.334
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e ₃		7.62			0.300	
F	3.8		4.0	0.150		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.020		0.050
M			0.68			0.027
S		8° (max.)				

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